

Superfluidity of Dense ^4He in Vycor

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We calculate properties of a model of ^4He in Vycor using the Path Integral Monte Carlo method. We find that ^4He forms a distinct layered structure with a highly localized first layer, a disordered second layer with some atoms delocalized and able to give rise to the observed superfluid response, and higher layers nearly perfect crystals. The addition of a single ^3He atom was enough to bring down the total superfluidity by blocking the exchange in the second layer. Our results are consistent with the persistent liquid layer model to explain the observations. Such a model may be relevant to the experiments on bulk solid ^4He , if there is a fine network of grain boundaries in those systems.

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There is a long history of experiments of helium absorbed in porous media carried out to probe the response of superfluidity to disorder [1]. Recently, Kim and Chan reported the observation of a supersolid Helium phase, in porous Vycor [2] and in bulk solid ^4He [3]. A supersolid [4] is a proposed phase of a quantum system in which long-range crystalline order and superfluidity coexist. We focus here on the measurements of the Helium-Vycor system.

The occurrence of supersolid behavior in Vycor, a disordered porous glass, could be understood from the properties of Vycor. One explanation is that the complex Vycor geometry stabilizes mobile defects which then undergo BEC at low temperatures $\approx 0.2\text{K}$. However, since the phenomenon is observed in bulk solid ^4He it is not the Vycor pores that are essential. Although, Kim and Chan pressurized their cell to 60 Bars, substantially above the estimated freezing pressure for helium in Vycor of 40 bars, even if most of the helium is solid, it is not clear if there remains a liquid film (the persistent liquid layer or PLL) near the Vycor-helium surface. The film could arise from the mismatch of lattice parameters as the density of ^4He varies from the center of the pores to their surface.

Even though there have been many experimental studies of helium in Vycor, there have been few microscopic calculations of the detailed microscopic structure of this system. Here we report on a model of the helium-Vycor system and calculate its properties with the Path Integral Monte Carlo (PIMC) method [5]. PIMC can calculate exact thermodynamic properties of bosonic systems such as ^4He at non-zero temperature by sampling the thermal density matrix $\rho \equiv e^{-\beta H}$, with $\beta = 1/k_B T$ and H the Hamiltonian. An explicit expression for the density matrix is obtained by expanding into a path and approximating the higher temperature density matrices. Bose statistics are obtained by symmetrizing the density matrix $\rho_{Bose}(R, R'; \beta) = \sum_P \rho(R, PR'; \beta)/N!$. PIMC proved accurate in studying properties in the normal liquid, superfluid and crystal phase [5]. In contrast to methods based on trial wavefunctions, in PIMC only the Hamiltonian enters, so no biases are made on the struc-

ture of the many-body system.

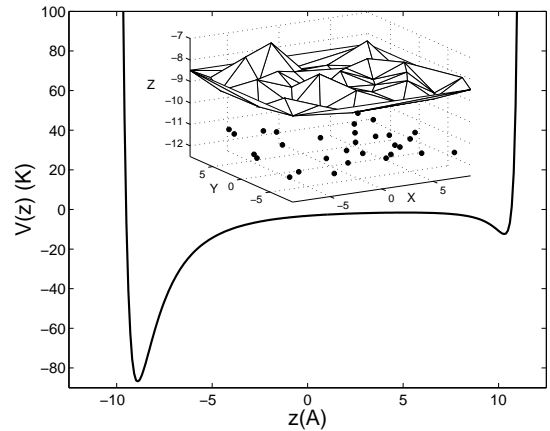


FIG. 1: The external potential $V(z)$ experienced by the helium atoms in “cell 2”. The Vycor is on the left side ($z=-12.5\text{\AA}$) and solid helium on the right side ($z=12.5\text{\AA}$). The inset is a 3D representation of the rough Vycor surface: the black dots are the positions of the Vycor impurities placed randomly at 1\AA away from the Vycor wall. The rugged surface shows the positions of the helium atoms (located at the vertices) in the first layer.

Vycor’s complex geometry is difficult to simulate directly. Under the transmission electron microscope, Vycor shows interconnected pores with diameters between 60\AA and 80\AA and a length of 300\AA , with a narrow distribution of pore sizes. Current simulation techniques treating all the atoms with PIMC are unable to simulate even a single pore (containing roughly 30000 atoms). It is thought that above the freezing pressure (40 bars) a ^4He crystal will occupy the center of a pore [6]. Previous PIMC calculations have found that a perfect crystal will not have a superfluid response at long wavelength [7]. Making this assumption, we study only the region near the surface of a pore and model it with the slab geometry: our simulation cell is periodic in both the x and y directions. In the negative z-direction there is a wall, representing bulk Vycor on top of which are placed

Vycor “particles” in random positions 1 Å above the flat Vycor surface. These particles serve to make the surface rough and break translational invariance. In the positive z -direction is a wall which models bulk solid Helium at a pressure of 62 bars (see Fig. 1).

The main input to PIMC is the interaction potential between various particles. We assume that the Helium-Helium interaction is given by the Aziz [8] potential which has been used within PIMC to study numerous other properties of helium and gives energies accurate to about 1% of the bulk binding energy. The potential between helium and the upper wall was derived by integrating an approximate LJ 6-12 potential ($\epsilon = 10.22K$ and $\sigma = 2.556\text{Å}$) over the volume $z > 11.7\text{Å}$ (cell 1) resulting in a LJ (3-9) potential.

We also assume helium-Vycor surface interaction is a LJ (3-9) potential [9]: $V(z) = \frac{D}{2}[(\frac{z_e}{z})^9 - 3(\frac{z_e}{z})^3]$. Since Vycor glass, SiO_2 , should behave similarly to MgO [10], we pick the well depth to be $D = -86.9K$, and the range of the attraction, $z_e = 3.6\text{Å}$. In order to pin the helium crystal in the xy plane and model the roughness of the Vycor, we add Vycor “particles” in random positions 1 Å above the wall. The interaction between the helium atoms and the Vycor particles is determined by demanding that a complete layer of the particles give the same LJ (3-9) potential. Experiments [11] show that the roughness in Vycor is on the scale of 0.8nm, not very different from what we have assumed. Figure 1 shows the wall potential and the surface roughness.

We set the helium density to match the experimental conditions by adjusting the number of helium atoms and the total area in the xy plane so that the helium density in the topmost layer matches that of solid ^4He at a target pressure close to 62 bars. We start the simulation with 221 atoms placed in 7 layers in an hexagonal closed packed solid phase. Each layer contains 30 atoms except for the first layer placed at the strongly attractive Vycor wall potential (Fig. 1). We have performed extensive simulations with two geometries, denoted as Cell 1 (221 He atoms with a box $17.75 \times 18.45 \times 23.4\text{Å}$) and Cell 2 (221 atoms with a box $17.25 \times 17.93 \times 25\text{Å}$). Cell 1 is roughly stress free, while Cell 2 provides us with a way to look at the model under anisotropic stress.

The density in the z -direction (see Fig. 2) shows a distinct layered structure of ^4He . The density increases as we approach the Vycor wall because of the stronger attraction of the potential well. The Vycor particles distort the shape of the density peak in the first layer because there are binding sites at different values of z . We find a perfect crystal is stable in the upper portion of the cell with a lattice constant of 3.55Å in cell 1 and 3.45Å in cell 2, at the target pressure of 62 bars. We estimate the pressure by calculating the density per layer from fig. 2 and comparing it with the experimental equation of state [12].

We determine the spatial ordering within a layer with

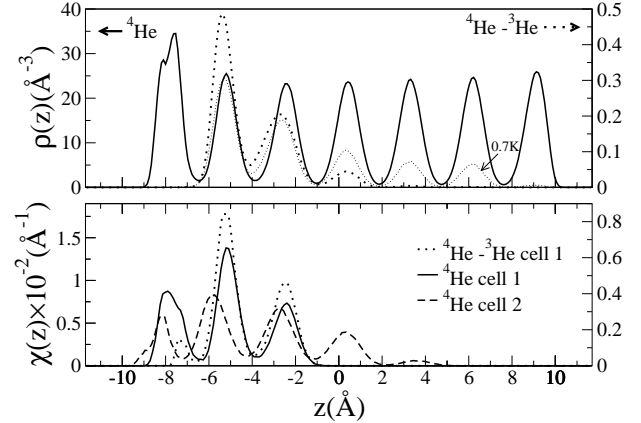


FIG. 2: The density and superfluid density as a function of z . The left scale (solid line) corresponds to pure ^4He and the right to the mixture: one ^4He atom replaced by a ^3He atom. Top: The density in the z -direction for cell 1 at 0.2K. The split peak in the first (leftmost) layer is due to the rough Vycor surface. The dotted lines show the ^3He density at 0.2K and 0.7K. Bottom: Local superfluid density of ^4He determined by recording which layers the winding paths visit; Eq. (3).

the structure factor in the x - y direction

$$S_n(\mathbf{k}) = \frac{1}{N} \langle \rho_n(\mathbf{k}) \rho_n(-\mathbf{k}) \rangle \quad (1)$$

where $\rho_n(\mathbf{k}) = \sum_{i=1}^N \Theta(z_i \in n) \exp(i\mathbf{k} \cdot \mathbf{r}_i)$ is the Fourier transform of the density within layer n and $\mathbf{k} = (k_x, k_y, 0)$. We can see the signature of a solid from the peak of $S(\mathbf{k})$ around $k_0 = 2.04\text{Å}^{-1}$ as shown in fig. 3 for cell 1; the peak clearly shows an hexagonal structure for layers three and above. The density profiles within a layer at the top of the figure confirm this interpretation. However, not all of the layers are solid. In fact, layer 1 is solid-like with the helium atoms well-localized but with their mean positions determined by the underlying disorder. Layer 2 is more disordered, and the atoms are out of register with the first layer. Because the second layer density is lower, the atoms are much less localized and, as we shall see, are able to become superfluid. Layers three and above are quantum solids, mostly free of defects. This is relatively independent of pressure, because of the strong Vycor potential shown in Fig. (1). We note that recent neutron scattering experiments [14] support the co-existence of solid-like and liquid-like layers at these pressures.

The superfluid fraction is computed in PIMC from the mean squared winding number [13], $\rho_s/\rho = m \langle W^2 \rangle / (2\beta \hbar^2 N)$ where N is the number of Helium atoms and $\mathbf{W} = \sum_{i,\mathbf{k}} (\mathbf{r}_{i,\mathbf{k}} - \mathbf{r}_{i,\mathbf{k}+1})$; the sum is over particles i , and time slices k . The superfluid fraction increases as we lower the temperature as shown in fig. 4 and approaches values of about 4% below 0.3 K.

To find the spatial distribution of the superfluid density, we divide the winding number estimator into local

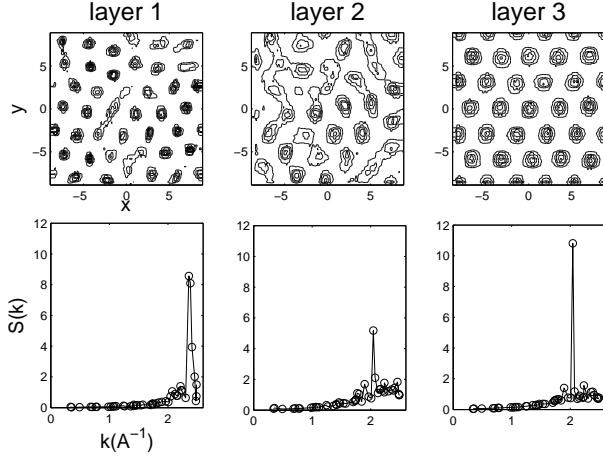


FIG. 3: Top: Contour plots of the helium density in the x-y plane in the first three layers at 0.2K for cell 1. In the first layer above the Vycor, the atoms are pinned by the strong Vycor interaction, in the second layer they are relatively delocalized, whereas the higher levels show a density distribution characteristic of bulk solid ^4He . Bottom: The layer-specific structure factor. The first layer has an amorphous structure, the second is still distorted but with a much smaller peak, while the third and higher layers have a single large peak at $k_o=2.04\text{\AA}^{-1}$ characteristic of a 2D quantum solid.

contributions that sum to the total superfluid density [15]. The superfluid density as a function of the distance above the Vycor wall $\chi(z)$ is:

$$\chi(z) = \frac{\sum_{k_{\text{slice}}, c_{\text{cycle}}} W_{k,c}^2 \delta(z_{k,c} - z)}{4\lambda\beta N}. \quad (2)$$

In fig. 2, we show $\chi(z)$ for $T=0.2\text{K}$ in cell 1. One can see the layered structure of the density. Layer 2 has the largest superfluid component. Layer one contributes because some atoms sit close to layer 2. Layer 3 is also active. The superfluid response goes to zero above layer 3. However, this decay is slower in cell 2 where the two additional layers (4 and 5) still contribute to ρ_s/ρ .

To compare with experiment we must make two corrections; first that our model has a larger fraction of atoms near the Vycor surface than experiment, and second that our cell has no tortuosity: the experimental path length for a superflow is greater than the straight line distance. We correct for the difference in Vycor surface area by assuming that the superfluidity is confined to a finite distance above the Vycor so that the effective number of atoms that do not respond to the moving boundaries is: $N_s = \sigma A$ where A is the Vycor surface area (actually the surface area of the mobile layer). We find that the maximum number of superfluid atoms per unit area is: $\sigma \approx 2.7\text{nm}^{-2}$. Then for a Vycor sample with experimental surface area per unit volume of $a = 0.2\text{nm}^{-1}$ the relative superfluid response would be $a\sigma_s/\mu\rho\kappa$ where $\mu = 0.3$ is the experimental Vycor sample pore fraction, $\kappa = 5$ is the tortuosity, and $\rho = 31.66\text{nm}^{-3}$ is the solid

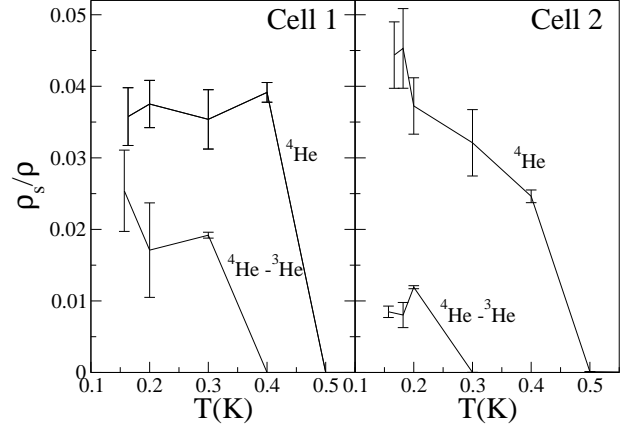


FIG. 4: The superfluid fraction ρ_s/ρ vs. temperature. The upper curve is for pure ^4He . The lower curve is for the system with a ^4He atom replaced by a ^3He atom.

number density. Using the experimental parameters of Vycor, we would predict a measured superfluid fraction of 0.011. In fact, Kim and Chan measure a value two times smaller than this. One important effect missing in our calculation is that the supercurrents must tunnel through various weak links, an aspect not present in our calculations because of the limited extent of the cell in the x-y directions. In addition, we have not taken the thermodynamic limit, though it is not obvious how to do this without a better model of the Vycor. We also note that the model is lacking important aspects of disorder, for example, that induced by the curvature of the pore and possible grain boundaries between the pores. Given these uncertainties, Kim and Chan’s measured values are well within the range expected from our calculations.

Recent experiments [16] do not find any indication that the liquid layer can flow in response to a pressure gradient. It is possible that there is an “insulating” (*e.g.* defect-free, see below) layer of solid ^4He which forms at the surface of the Vycor samples and blocks the superflow.

Kim and Chan also studied the effect of ^3He impurities on the measurement of the superfluid density. Accordingly, we replaced a single ^4He with a ^3He atom. (Note that we do not need to consider fermi statistics for a single fermion). This corresponds to roughly 0.3% concentration of ^3He (assuming our cell size is $\approx 2/3$ of the pore). Experimentally, this concentration was enough to destroy any “supersolid” response. With local moves the system was slow to reach equilibrium: we used a move that swapped the identity of the impurity with a random ^4He atom. PIMC with the new procedure quickly reached equilibrium.

The impurity, being lighter than ^4He , has a larger kinetic energy and hence a larger atomic volume. This extra space is available in the second liquid-like layer. Also, the ^3He atom does not exchange with the ^4He and

thus reduces the superfluid density in its neighborhood. The density profiles show that the ^3He impurity preferentially goes to the same site where the superfluidity is maximized (Fig. 2). At higher temperatures, it tunnels to other layers with an excitation energy of 0.8K. As the temperature is lowered, two competing effects take place. The ^4He atoms nearest to the Vycor surface exchange resulting in superfluidity. However, the ^3He atom migrates towards the most superfluid layers, hence reducing the superfluid response and a shift towards a lower transition temperature, see fig. 4. It is plausible that in a larger cell, an even smaller concentration of ^3He could pinch off the winding exchanges (or supercurrent) by going to choke positions not present in our small cell, thus giving better agreement with the experimental findings of a critical ^3He concentration of 0.1%.

Kim and Chan [2] mention two pieces of evidence to argue against the liquid film interpretation. First, the observed temperature dependence of the superfluid density is unlike that of films. However, the films under pressure are totally enclosed within a solid and they are not like films forming an interface between a solid and a vacuum; as we have seen, there are low energy excitations giving rise to pronounced temperature effects, not present in the later case. Also, the connectivity whether primarily 2D or 3D, of these solid-enclosed films could be different; it is likely that they are gossamery, as opposed to the robust films resulting when the pores are only partially filled. The second effect mentioned by Kim and Chan is the poisoning by small amounts of ^3He . This does not happen in free films because the ^3He atom is above the plane of the ^4He film in a delocalized state and thus is not effective in preventing ^4He exchanges.

The liquid-layer scenario can be used to give insight into the other porous media and bulk helium experiments. Let us assume that the observed superfluidity is due to surface superfluidity as proposed by Burovski et al. [17] and that the helium microcrystals are roughly spherical with a diameter of R , giving a surface to volume ratio of $a = 3/R$. Arguing as before, to obtain the observed 2% superfluid response of bulk ^4He , we must have that $R = 3\sigma/(\kappa\rho_s)$ where σ is the superfluid density per unit area at the crystal interfaces. It is reasonable to expect that σ is considerably larger than at the interface between helium and Vycor, since the pressure exerted by the silica increases the density and hence decreases the mobility of the helium atoms. Let us assume that there are 2 complete superfluid layers at the interface giving $\sigma \approx 20\text{nm}^{-2}$. Given that the grain boundaries are larger and less fractal, we might expect that $\kappa \approx 2$. Using the experimental ρ_s for bulk ^4He , we find the average grain size, $R = 50\text{nm}$. It is quite likely that ^3He will stabilize the grain boundaries, thus explaining how such a small concentration of ^3He can affect the response. Such speculation need to be confirmed by performing experiments

on much better crystals and measuring the density and the sizes of grains.

Our results show superfluidity is localized in specific layers of ^4He above a Vycor surface. We obtain a superfluid response about 2 times what is observed, but the difference is likely due to the very small simulation cells we used that do not have the full range of the random disorder and crystal defects. We also found that ^3He impurities gravitate to the same spatial locations as the superfluid density, thus poisoning the effect. Based on these simulations, the persistent liquid layer interpretation of the Kim-Chan experiment seems not to be ruled out. Further studies with larger cells and more realistic disorder are needed to firm up these conclusions and to see if this mechanism, when involving grain boundaries, could give rise to the phenomena in bulk solid helium.

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